

CMOS Digital Integrated Circuits Silicon Monolithic

74VHCV240FT,74VHCV244FT

1. Functional Description

· Octal Schmitt Bus Buffer

74VHCV240FT: Inverted, 3-State Outputs 74VHCV244FT: Non-Inverted, 3-State Outputs

2. General

The 74VHCV240FT and 74VHCV244FT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHCV240FT is an inverting 3-state buffer having two active-low output enables. The 74VHCV244FT is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

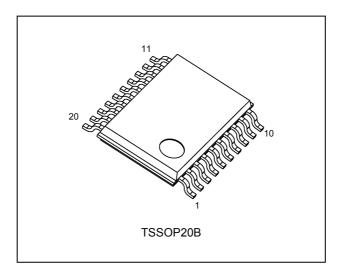
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 3.9 \text{ ns (typ.)}$ at $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 2.0 \mu A$ (max) at $T_a = 25 \, ^{\circ}C$
- (5) Wide operating voltage range: $V_{CC(opr)} = 1.8 \text{ V}$ to 5.5 V
- (6) Output current: $|I_{OH}|/I_{OL} = 16 \text{ mA (min)}(V_{CC} = 4.5 \text{ V})$
- (7) Power-down protection provided on all inputs.
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 240 or 244 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

4. Packaging



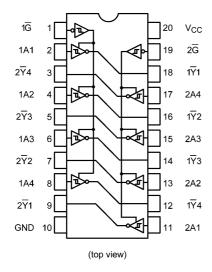
Start of commercial production

2014-07

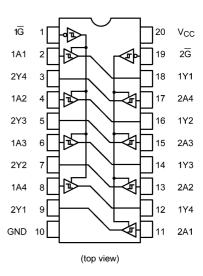


5. Pin Assignment

74VHCV240FT

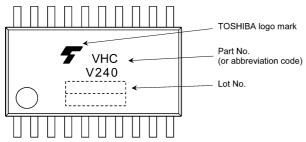


74VHCV244FT

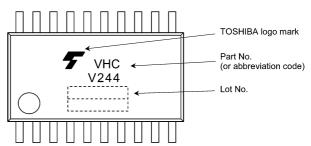


6. Marking

74VHCV240FT



74VHCV244FT



7. Truth Table

Input G	Input An	Output \overline{Y} n	
L	L	Н	
L	Н	Н	L
Н	Х	Z	Z

X: Don't care

Z: High impedance Yn: 74VHCV244FT Yn: 74VHCV240FT



8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	٧
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-50	mA
Output diode current	I _{OK}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	P _D	(Note 4)	180	mW
V _{CC} /ground current	I _{CC}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Output in OFF state.
- Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.
- Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$
- Note 4: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

9. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}		_	1.8 to 5.5	V
Input voltage	V _{IN}		_	0 to 5.5	٧
Output voltage	V _{OUT}	(Note 1)	_	0 to 5.5	V
		(Note 2)	_	0 to V _{CC}	
Operating temperature	T _{opr}		_	-40 to 125	∞
Input rise and fall times	dt/dv		V_{CC} = 3.3 ± 0.3 V	0 to 20	ms/V
			V_{CC} = 5.0 \pm 0.5 V	0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.



10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V_P	_	_		_	_	1.65	V
				2.3	_	_	1.85	
				3.0	_	_	2.20	
				4.5	_	_	3.15	
				5.5	_	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	_	V
				2.3	0.45	_	_	
				3.0	0.90	_	_	
				4.5	1.35	_	_	
				5.5	1.65	_	_	
Hysteresis voltage	V _H	_		1.8	0.15	_	1.05	V
				2.3	0.20	_	1.10	
				3.0	0.30	_	1.20	
				4.5	0.40	_	1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	1.8	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -8 mA	3.0	2.58	_	_	
			I _{OH} = -16 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 8 mA	3.0	_	_	0.36	
			I _{OL} = 16 mA	4.5	_	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	_	±0.5	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	_	0.5	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		_	±0.1	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	2.0	μА



10.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		1.8	_	1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	V
				2.3	0.45	_	
				3.0	0.90	_	
				4.5	1.35	_]
				5.5	1.65	_	
Hysteresis voltage	V _H	_		1.8	0.15	1.05	V
				2.3	0.20	1.10]
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60]
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_]
			I _{OH} = -8 mA	3.0	2.48	_	
			I _{OH} = -16 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1]
			I _{OL} = 8 mA	3.0	_	0.44]
			I _{OL} = 16 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	±5.0	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	5.0	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	20.0	μА



10.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	า	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_	1.8		1.65	V	
				2.3		1.85	
				3.0	_	2.20	
				4.5		3.15	
				5.5		3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	\ \
				2.3	0.45	_	
				3.0	0.90	_	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	_		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -8 mA	3.0	2.40	_	
			I _{OH} = -16 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 8 mA	3.0	_	0.55	
			I _{OL} = 16 mA	4.5	_	0.65	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	±20.0	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0		20.0	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±2.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	40.0	μА



10.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHCV240FT	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	_	6.4	11.6	ns
						50	_	9.2	14.4	
					3.3 ± 0.3	15	_	5.0	7.5	
						50	_	7.0	11.0	
					5.0 ± 0.5	15	_	3.9	5.5	
						50	_	5.4	7.5	
Propagation delay time	74VHCV244FT	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	_	6.7	12.5	ns
						50	_	9.5	15.3	
					3.3 ± 0.3	15	_	5.0	8.4	
						50	_	7.2	11.9	
					5.0 ± 0.5	15	_	3.8	5.5	
						50	_	5.4	7.5	
3-state output enable time		t_{PZL},t_{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	_	7.8	14.6	ns
						50	_	11.1	17.8	
					3.3 ± 0.3	15	_	5.7	10.6	
						50	_	8.4	14.1	
					5.0 ± 0.5	15	_	4.1	7.3	
						50	_	6.2	9.3	
3-state output disable time		t_{PLZ},t_{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	_	14.3	19.2	ns
					3.3 ± 0.3	50	_	10.9	14.0	
					5.0 ± 0.5	50	_	8.7	9.2	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	_	2.0	ns
					3.3 ± 0.3	50	_	_	1.5	
					5.0 ± 0.5	50	_	_	1.0	
Input capacitance		C _{IN}		_	•		_	4	10	pF
Output capacitance		C _{OUT}		_			_	6	_	pF
Power dissipation	74VHCV240FT	C _{PD}	(Note 2)	_			_	20	_	pF
capacitance	74VHCV244FT	C _{PD}	(Note 2)	_			_	21	-	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.



10.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_f = t_f = 3 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCV240FT	t_{PLH}, t_{PHL}		_	2.5 ± 0.2	15	1.0	14.0	ns
						50	1.0	17.0	
					3.3 ± 0.3	15	1.0	9.0	
						50	1.0	12.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
Propagation delay time	74VHCV244FT	t_{PLH}, t_{PHL}		_	2.5 ± 0.2	15	1.0	15.0	ns
						50	1.0	18.0	
					3.3 ± 0.3	15	1.0	10.0	
						50	1.0	13.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	1.0	17.0	ns
						50	1.0	21.0	
					3.3 ± 0.3	15	1.0	12.5	
						50	1.0	16.0	
					5.0 ± 0.5	15	1.0	8.5	
						50	1.0	10.5	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	1.0	21.0	ns
					3.3 ± 0.3	50	1.0	16.0	
					5.0 ± 0.5	50	1.0	10.5	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	2.5 ± 0.2	50		2.0	ns
					3.3 ± 0.3	50		1.5	
					5.0 ± 0.5	50		1.0	
Input capacitance		C _{IN}		_				10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$



10.6. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCV240FT	t_{PLH}, t_{PHL}		_	2.5 ± 0.2	15	1.0	16.0	ns
						50	1.0	19.0	
					3.3 ± 0.3	15	1.0	10.5	
						50	1.0	14.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	9.5	
Propagation delay time	74VHCV244FT	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	1.0	17.0	ns
						50	1.0	20.0	
					3.3 ± 0.3	15	1.0	11.5	
						50	1.0	15.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	9.5	
3-state output enable time		t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	1.0	19.0	ns
						50	1.0	23.5	
					3.3 ± 0.3	15	1.0	14.5	
						50	1.0	18.0	
					5.0 ± 0.5	15	1.0	10.0	
						50	1.0	12.0	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	1.0	22.5	ns
					3.3 ± 0.3	50	1.0	17.5	
					5.0 ± 0.5	50	1.0	11.5	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	2.0	ns
					3.3 ± 0.3	50	_	1.5	
					5.0 ± 0.5	50	_	1.0	
Input capacitance		C _{IN}		_	•		_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

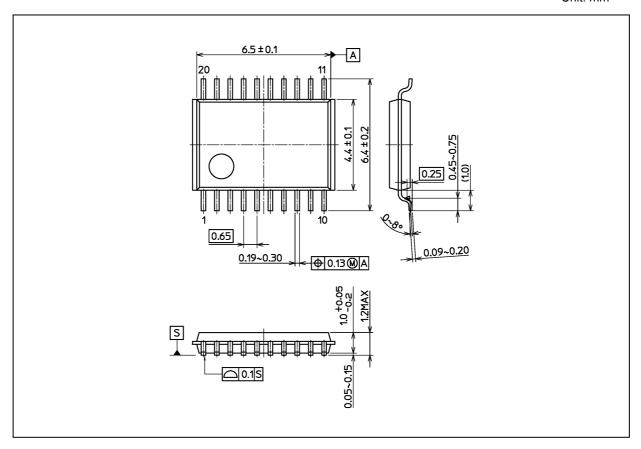
10.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	3.3	0.45	_	V
			5.0	0.9	_	
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1	_	V
			5.0	-0.3	_	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0		3.5	V
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	



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